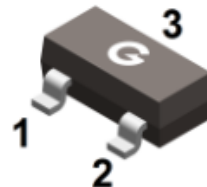
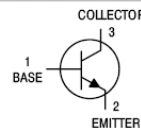


Features

- Epitaxial planar die construction
- Complementary PNP type available(TMMBTA56)
- RoHS compliant with Halogen-free
- Qualified to AEC-Q101 Standards

HF



SOT-23

Mechanical Data

- Case: SOT-23
- Molding compound: UL flammability classification rating 94V-0
- Terminals: Tin-plated; solderability per MIL-STD-202, Method 208

Ordering Information

Part Number	Package	Shipping Quantity	Marking Code
TMMBTA06	SOT-23	3000 pcs / Tape & Reel	1GM

Maximum Ratings (@ T_A = 25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	80	V
Collector-Emitter Breakdown Voltage	V _{CEO}	80	V
Emitter-Base Breakdown Voltage	V _{EBO}	4	V
Collector Current (Continuous)	I _C	0.5	A
Collector Current (Peak)	I _{CM}	1	A
Base Current	I _B	0.2	A

Thermal Characteristics

Parameter	Symbol	Value	Unit
Power Dissipation	P _D	0.35	W
Thermal Resistance Junction-to-Air ^{*1}	R _{θJA}	258	°C/W
Thermal Resistance Junction-to-Case ^{*1}	R _{θJC}	142	°C/W
Thermal Resistance Junction-to-Lead ^{*1}	R _{θJL}	186	°C/W
Junction Temperature Range	T _J	-55 ~ +150	°C
Storage Temperature Range	T _{STG}	-55 ~ +150	°C

Note 1: The data tested by surface mounted on a 15mm * 15mm * 1mm FR4-epoxy P.C.B

Electrical Characteristics (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

Parameter	Symbol	Test Condition	Min.	Typ.	Max.	Unit
Collector-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = 100\mu\text{A}$, $I_E = 0$	80	-	-	V
Collector-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = 1\text{mA}$, $I_B = 0$	80	-	-	V
Emitter-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = 10\mu\text{A}$, $I_C = 0$	4	-	-	V
Collector Cut-off Current	I_{CBO}	$V_{CB} = 80\text{V}$, $I_E = 0$	-	-	100	nA
Collector Cut-off Current	I_{CES}	$V_{CE} = 60\text{V}$, $I_B = 0$	-	-	100	nA
DC Current Gain	h_{FE}	$V_{CE} = 1\text{V}$, $I_C = 10\text{mA}$	100	-	-	-
		$V_{CE} = 1\text{V}$, $I_C = 100\text{mA}$	100	-	-	-
Collector-emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = 100\text{mA}$, $I_B = 10\text{mA}$	-	-	0.25	V
Base-emitter Voltage	$V_{BE(ON)}$	$I_C = 100\text{mA}$, $V_{CE} = 1\text{V}$	-	-	1.20	V
Current-Gain— Bandwidth Product	f_T	$I_C = 20\text{mA}$, $V_{CE} = 5\text{V}$ $f = 20\text{MHz}$	100	-	-	MHz

Ratings and Characteristics Curves (@ $T_A = 25^\circ\text{C}$ unless otherwise specified)

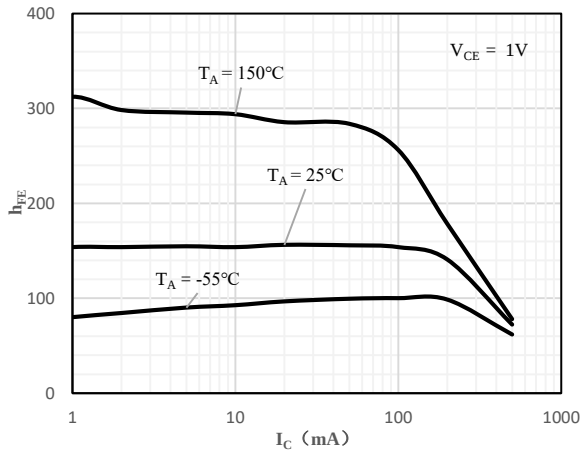


Fig 1 h_{FE} vs. I_C

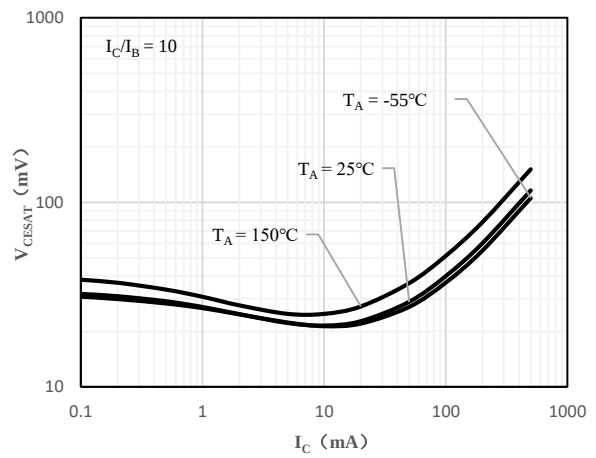


Fig 2 $V_{CE(sat)}$ vs. I_C

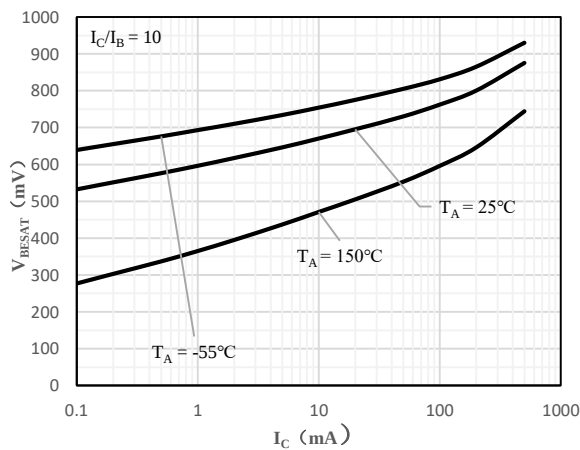


Fig 3 $V_{BE(sat)}$ vs. I_C

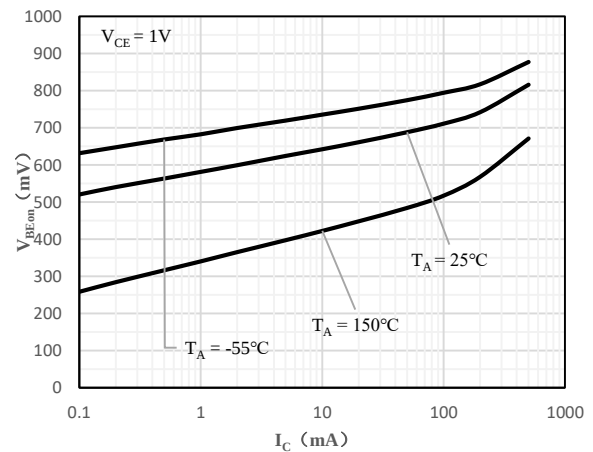


Fig 4 $V_{BE(on)}$ vs. I_C

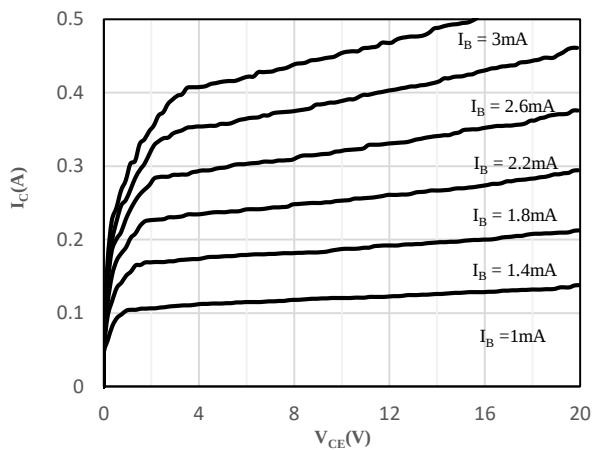


Fig 5 I_C vs. V_{CE}

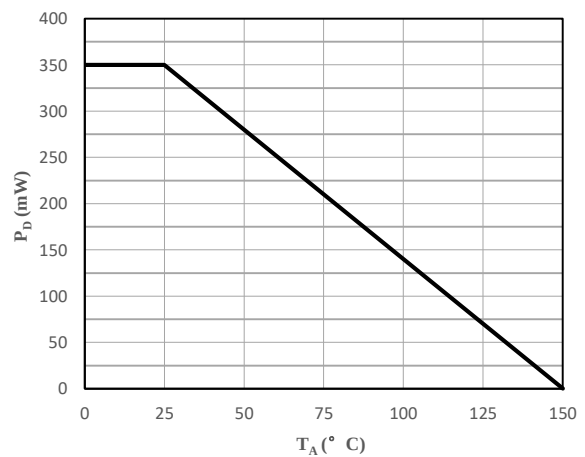


Fig 6 P_D vs. T_A

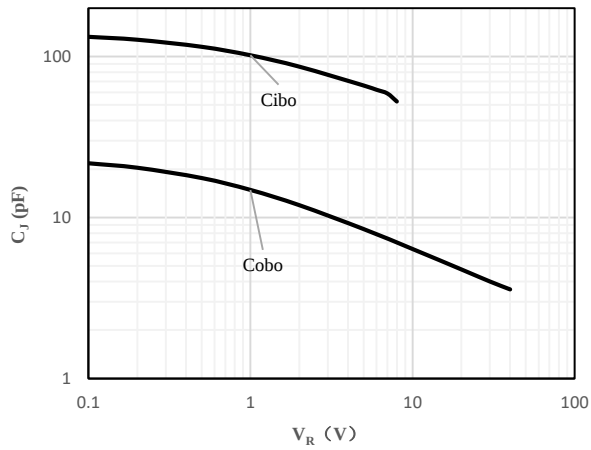
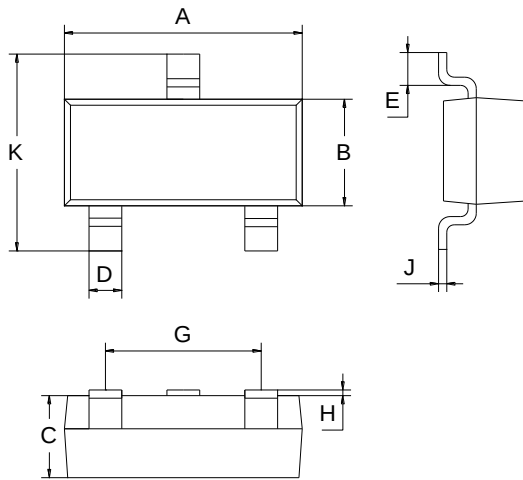


Fig 7 C_J vs. V_R

Package Outline Dimensions (Unit: mm)



SOT-23		
Dimension	Min.	Max.
A	2.70	3.10
B	1.10	1.50
C	0.90	1.10
D	0.30	0.50
E	0.35	0.48
G	1.80	2.00
H	0.02	0.10
J	0.05	0.15
K	2.20	2.60

Package Outline Dimensions (Unit: mm)

SOT-23

